

# **Four Layer P-N-P-N Switching Devices (Uni Junction Transistor)**

## **Lecture – 4**

**TDC PART – II  
Paper - III (Group - A)  
Chapter - 4**

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## Lecture – 4

TDC PART – II

Paper - III (Group - A)

Chapter - 4

- (Uni Junction Transistor)

- Lecture Content :-

- UJT Parameters

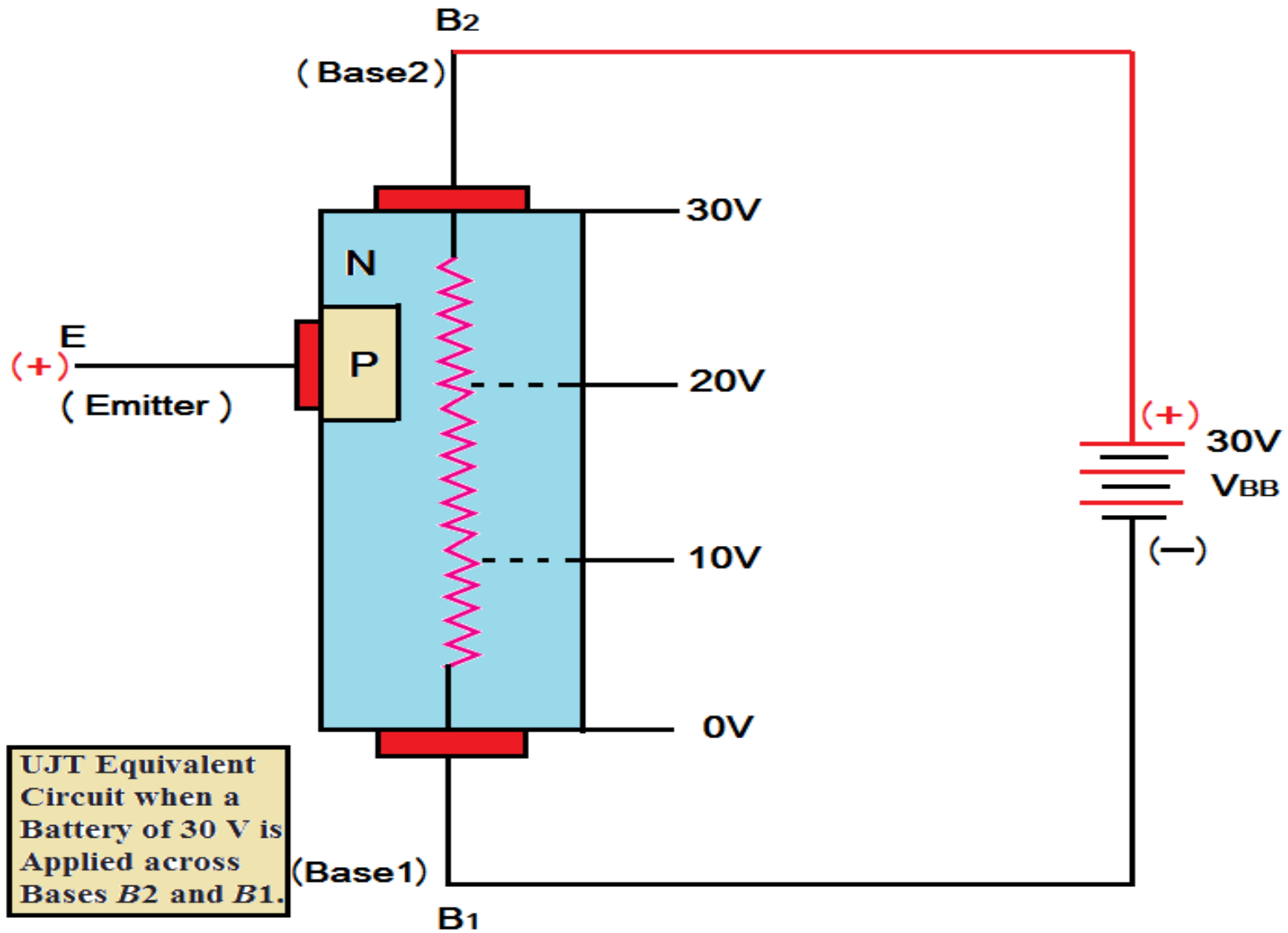
- (2) Intrinsic Stand-off Ratio ( $\eta$ ) by 1st Method

# UJT Parameters

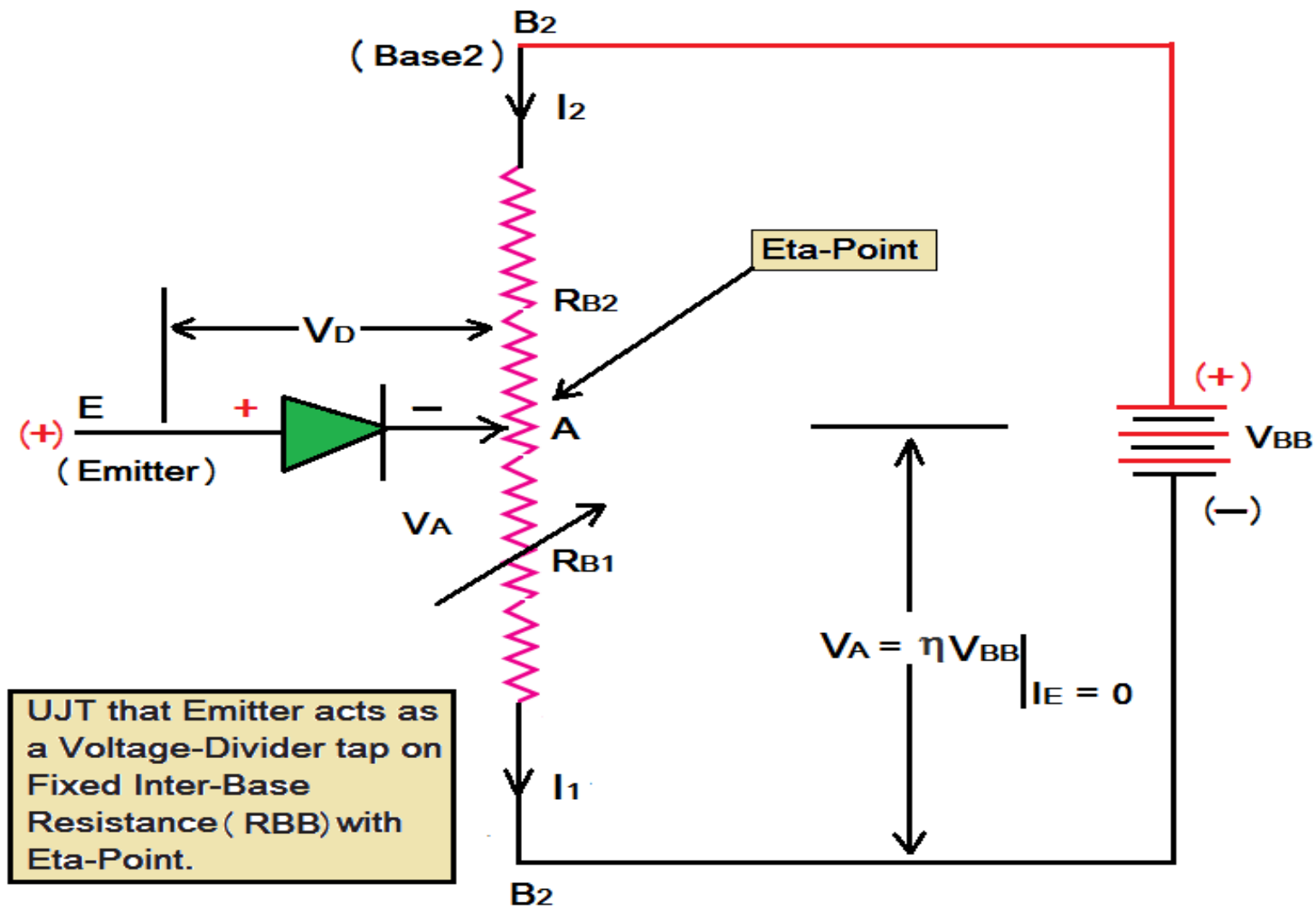
## (2) Intrinsic Stand-off Ratio ( $\eta$ ) by 1st Method

- As seen from **Figure (11)** below when a battery of **30 V** is applied across **(Base2) B2** and **(Base1) B1**, there is a progressive fall of voltage over **R<sub>BB</sub>** provided **Emitter (E) Terminal** is open. It is obvious from **Figure (12)** that Emitter acts as a **Voltage-Divider** tap on fixed Resistance **R<sub>BB</sub>**. With **Emitter (E)** open, **I<sub>1</sub> = I<sub>2</sub>**, the **Inter-base Current** is given by **Ohm's Law**.

- $$I_1 = I_2 = V_{BB} / R_{BB}$$



- Fig (11) Shown UJT Equivalent Circuit when a Battery of 30 V is applied across Base B2 and B1.



UJT that Emitter acts as a Voltage-Divider tap on Fixed Inter-Base Resistance ( $R_{BB}$ ) with Eta-Point.

- Fig (12) Shown UJT that Emitter acts as a Voltage-Divider tap on Fixed Inter Base Resistance ( $R_{BB}$ ) with Eta – Point.

- **For example:** - If  $V_{BB} = 30 \text{ V}$  and  $R_{BB} = 15 \text{ K}$ ,  
 $I_1 = I_2 = 2 \text{ mA}$ .
- It may be noted that part of  $V_{BB}$  is dropped over  $R_{B2}$  and part on  $R_{B1}$ . Let us call the voltage drop across  $R_{B1}$  as  $V_A$ . Using simple **voltage divider** relationship,
- $V_A = V_{BB} (R_{B1} / R_{B1} + R_{B2})$

- The **voltage division factor** is given a special symbol (  $\eta$  ) and the name of ‘**Intrinsic Stand – off Ratio**’. **Intrinsic Stand – off Ratio** is the ratio of **R<sub>B1</sub>** to the sum of **R<sub>B1</sub>** and **R<sub>B2</sub>**. It can be expressed as,

- $$\eta = R_{B1} / R_{B1} + R_{B2}$$

- $$V_A = \eta V_{BB}$$

- The **Intrinsic Stand-off Ratio** ( $\eta$ ) is the property of the **UJT** and is always **Less than Unity (0.4 to 0.85)**. If  $V_{BB} = 30 \text{ V}$  and  $\eta = 0.6$ , then potential of **Point A** with respect to **Point B1**  $= 0.6 \times 30 = 18 \text{ V}$ . The remaining **12 V** drop across **R<sub>B2</sub>**.



**to be continued .....**